



IEC TS 62804-1:2015

Photovoltaic (PV) Modules - Test Methods for the detection of potential-induced degradation

Part 1: Crystalline silicone
Confirmation of test results

Ref.: 10036/2021-40216

Applicant: LG Electronics Inc.
168, Suchul-daero, Gumi-si, Gyeongsangbuk-do,
730-903, South Korea

Product: Crystalline Silicon Photovoltaic (PV)-Modules

Type: A) LGXXN3C-V6
LGXXN3W-V6
B) LGXXN3K-V6

XXX in the type replace the power in Watt and can be any number between: 395 – 415 for A), 390 – 410 for B).

Manufacturer: LG Electronics Inc.

Standard: IEC TS 62804-1:2015

Test conditions:

Testing time:	96 h
Chamber temperature:	85°C
Relative Humidity:	85 %
Potential to ground:	+/- 1000 V

Pass criteria:

Power degradation:	<3%
Wet insulation resistance:	>40 MΩ
Dry insulation resistance:	>40 MΩ
Visual Inspection:	No findings



Summary of test results:

Maximum power degradation:	allowed	max. 3 %
	measured	max. 0.89 %

The measured degradation is below the max. allowed degradation.

Wet insulation resistance:	required	min. 20.4 MΩ
	measured	>999 MΩ

The measured wet insulation resistance is above the min. required wet insulation resistance.

Dry insulation resistance:	required	min. 20.4 MΩ
	measured	>999 MΩ

The measured dry insulation resistance is above the min. required dry insulation resistance.

Visual inspection: No findings

The complete test results and the relevant bill of materials are given in Test Report No.: TRPVM-2021-40216-1.

VDE Renewables GmbH


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